



US 20130335665A1

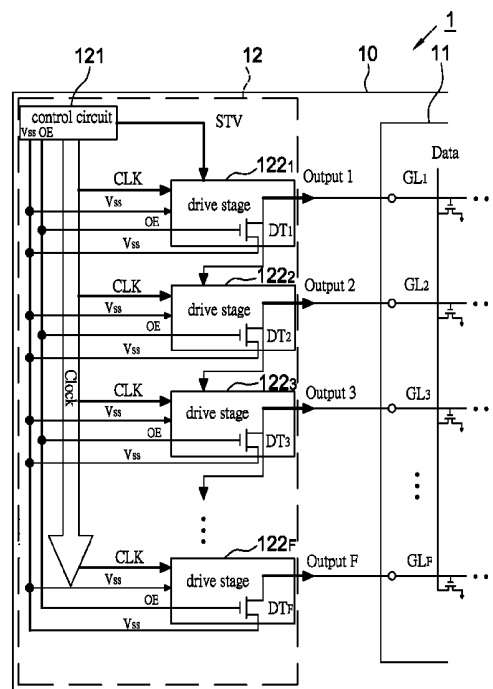
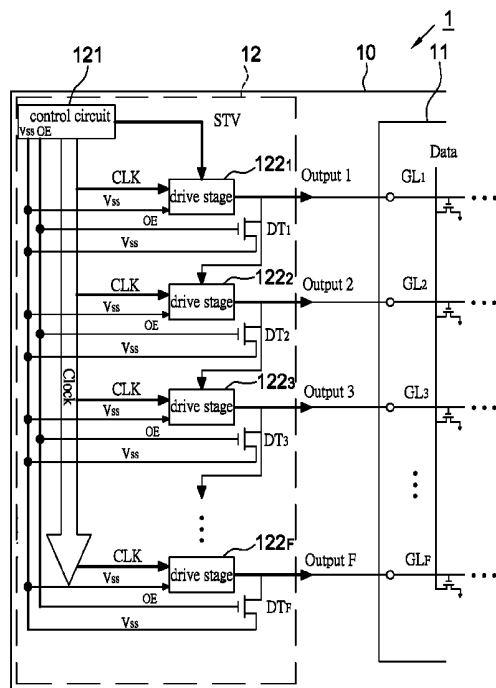
(19) **United States**(12) **Patent Application Publication**
TSENG et al.(10) **Pub. No.: US 2013/0335665 A1**(43) **Pub. Date: Dec. 19, 2013**(54) **INTEGRATED GATE DRIVER CIRCUIT AND
LIQUID CRYSTAL PANEL****Publication Classification**(51) **Int. Cl.****G02F 1/133** (2006.01)**H03K 17/16** (2006.01)(52) **U.S. Cl.**CPC **G02F 1/13306** (2013.01); **H03K 17/16**
(2013.01)USPC **349/43; 327/109**(71) Applicant: **HANNSTAR DISPLAY CORP.**, New
Taipei City (TW)(72) Inventors: **Chun-Chin TSENG**, Kaohsiung (TW);
Ya-Wen Lee, Tainan (TW); **Kuo-Wen
Pan**, Kaohsiung City (TW)(73) Assignee: **HannStar Display Corp.**, New Taipei
City (TW)(21) Appl. No.: **13/771,806**(22) Filed: **Feb. 20, 2013**(30) **Foreign Application Priority Data**

Jun. 14, 2012 (CN) 201210198895.5

(57)

ABSTRACT

An integrated gate driver circuit includes a control circuit, a plurality of drive stages and a plurality of discharge transistors. The control circuit is configured to output a plurality of clock signals within a frame period and to output a discharge enabling signal within a blanking period of the frame period. Each of the drive stages receives the clock signals and includes an output terminal configured to output a gate driving signal. Each of the discharge transistors is coupled to the output terminal of one of the drive stages and discharges the output terminal according to the discharge enabling signal thereby eliminating the voltage fluctuation of the output terminal in the blanking period.



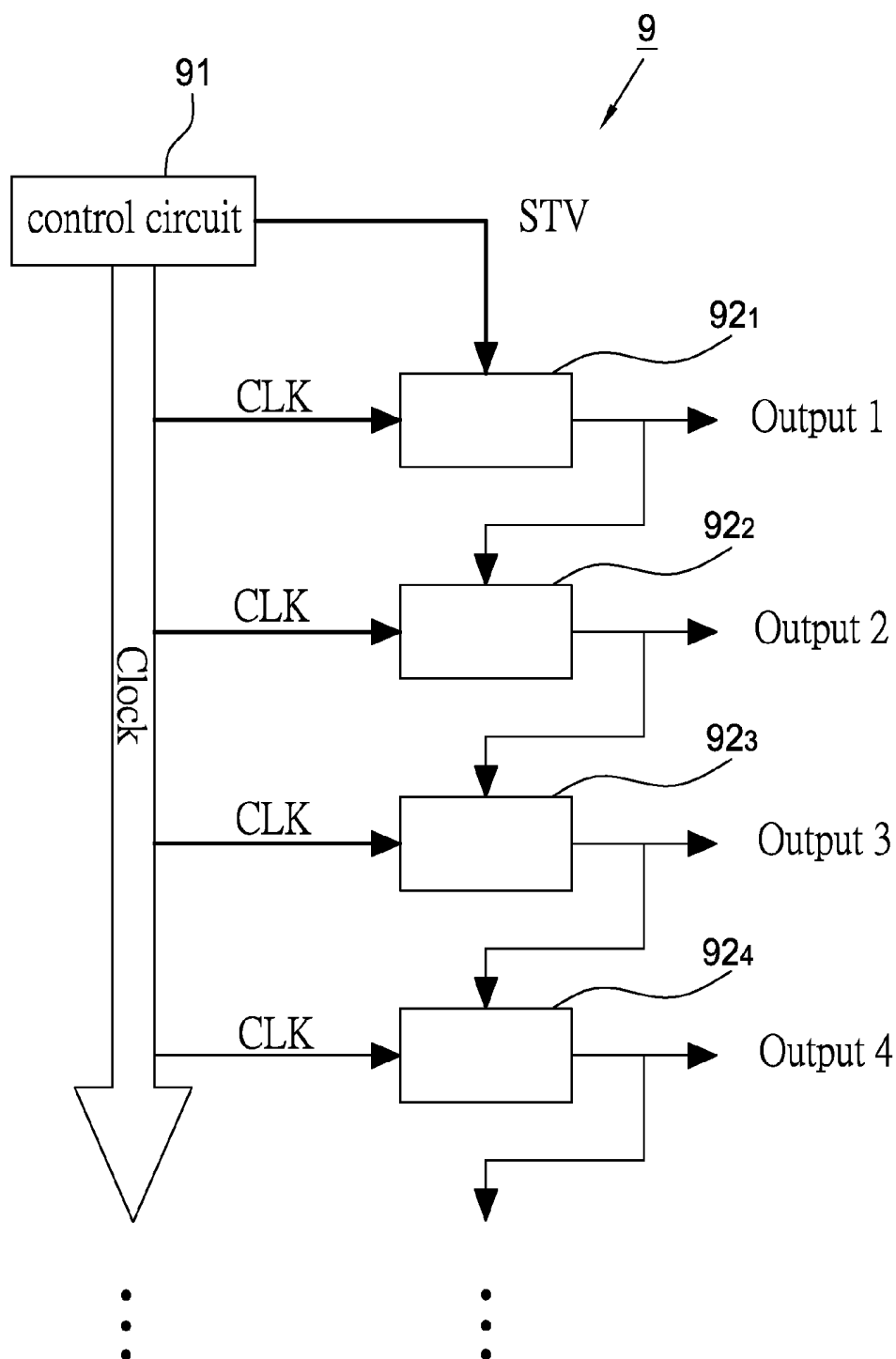


FIG. 1 (PRIOR ART)

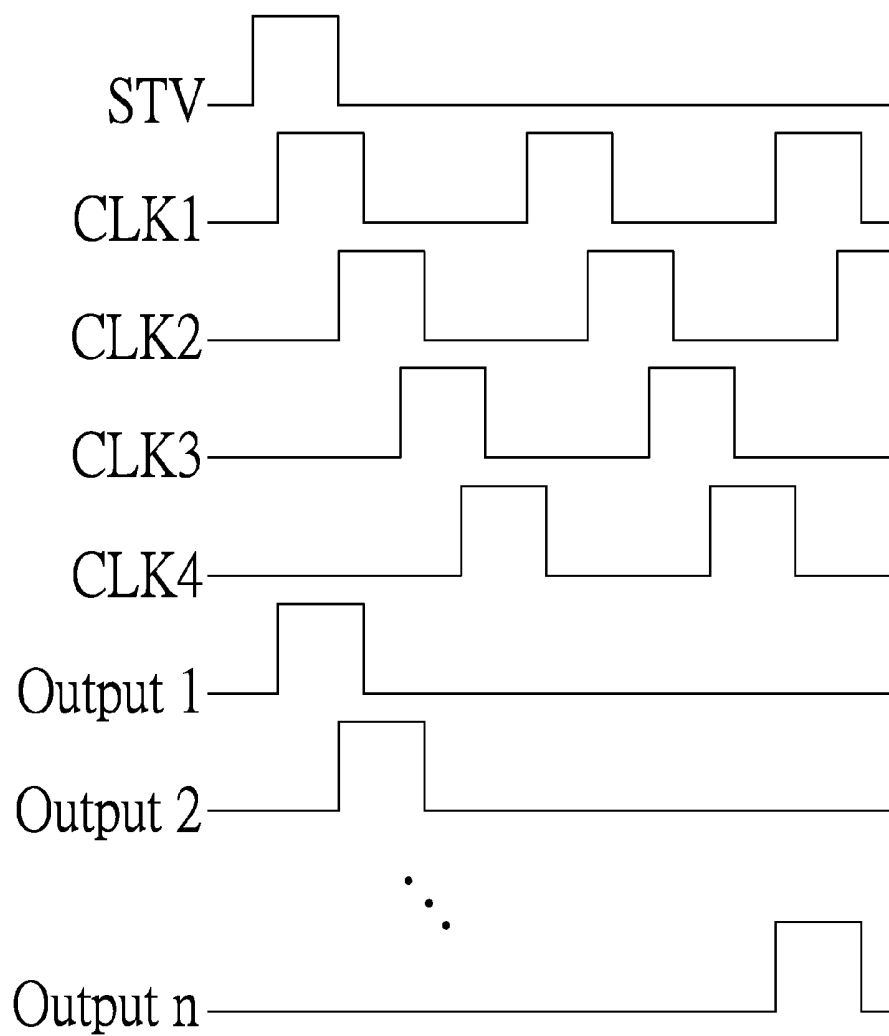


FIG. 2 (PRIOR ART)

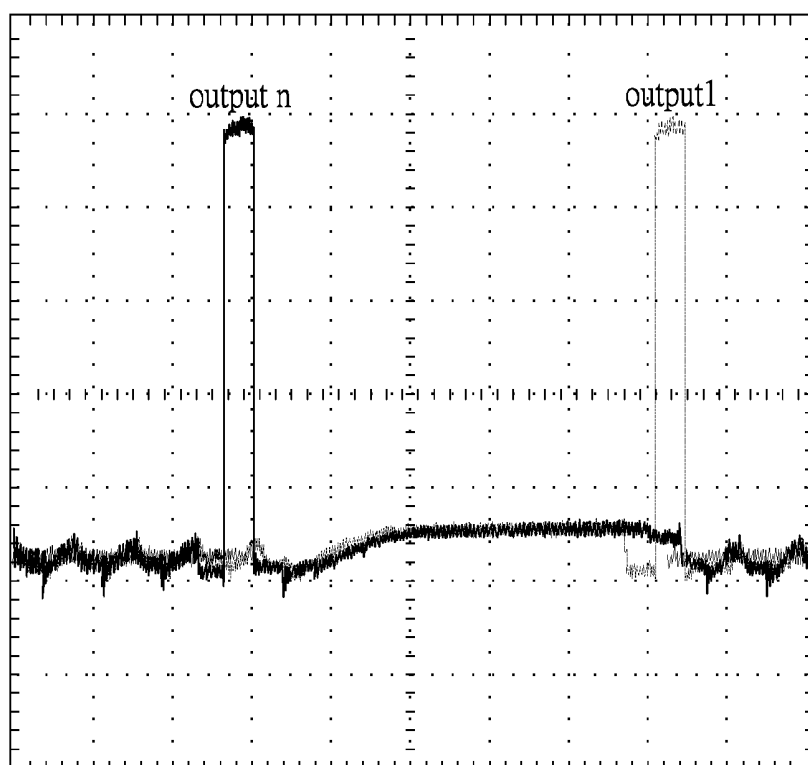


FIG. 3 (PRIOR ART)

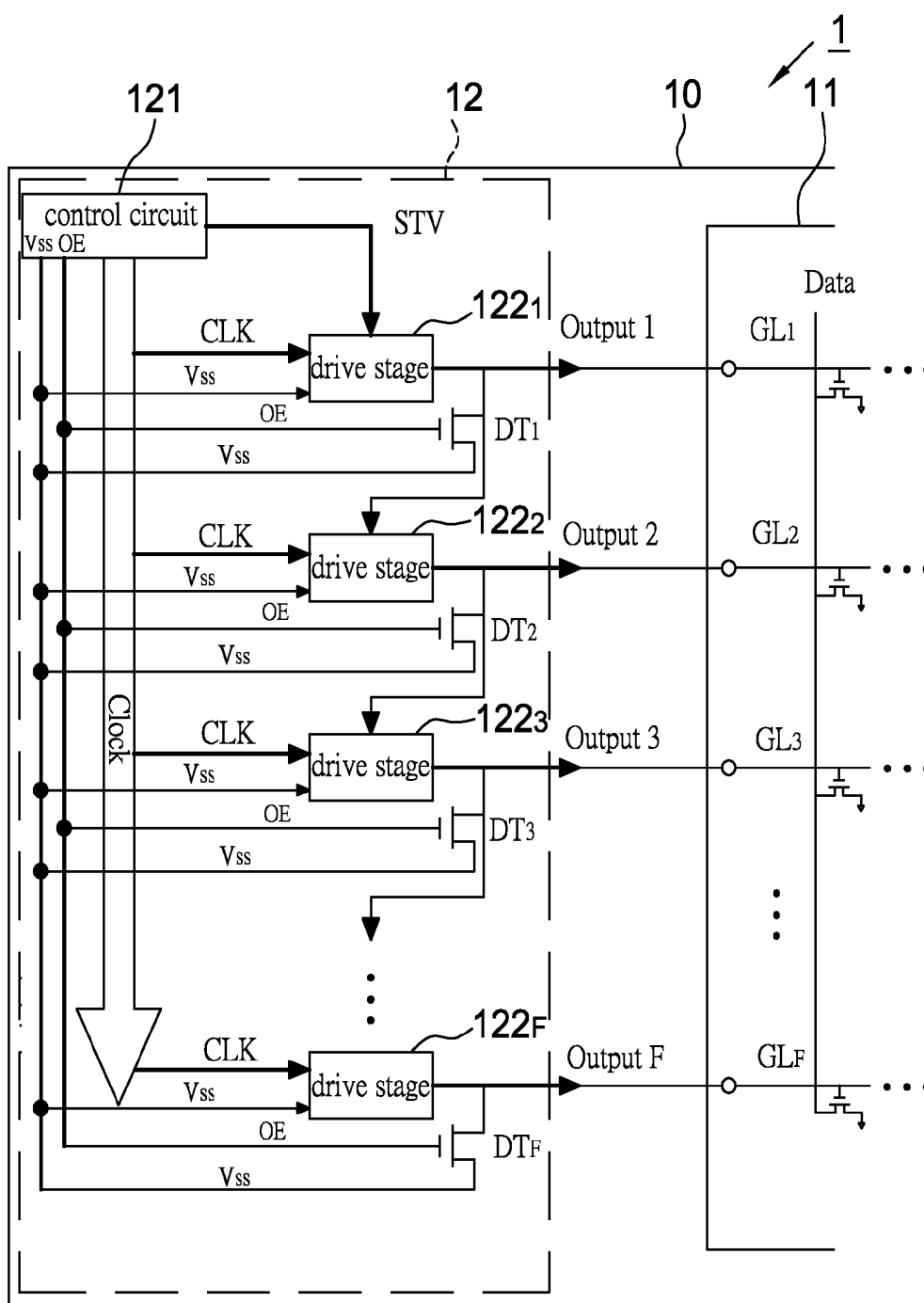


FIG. 4A

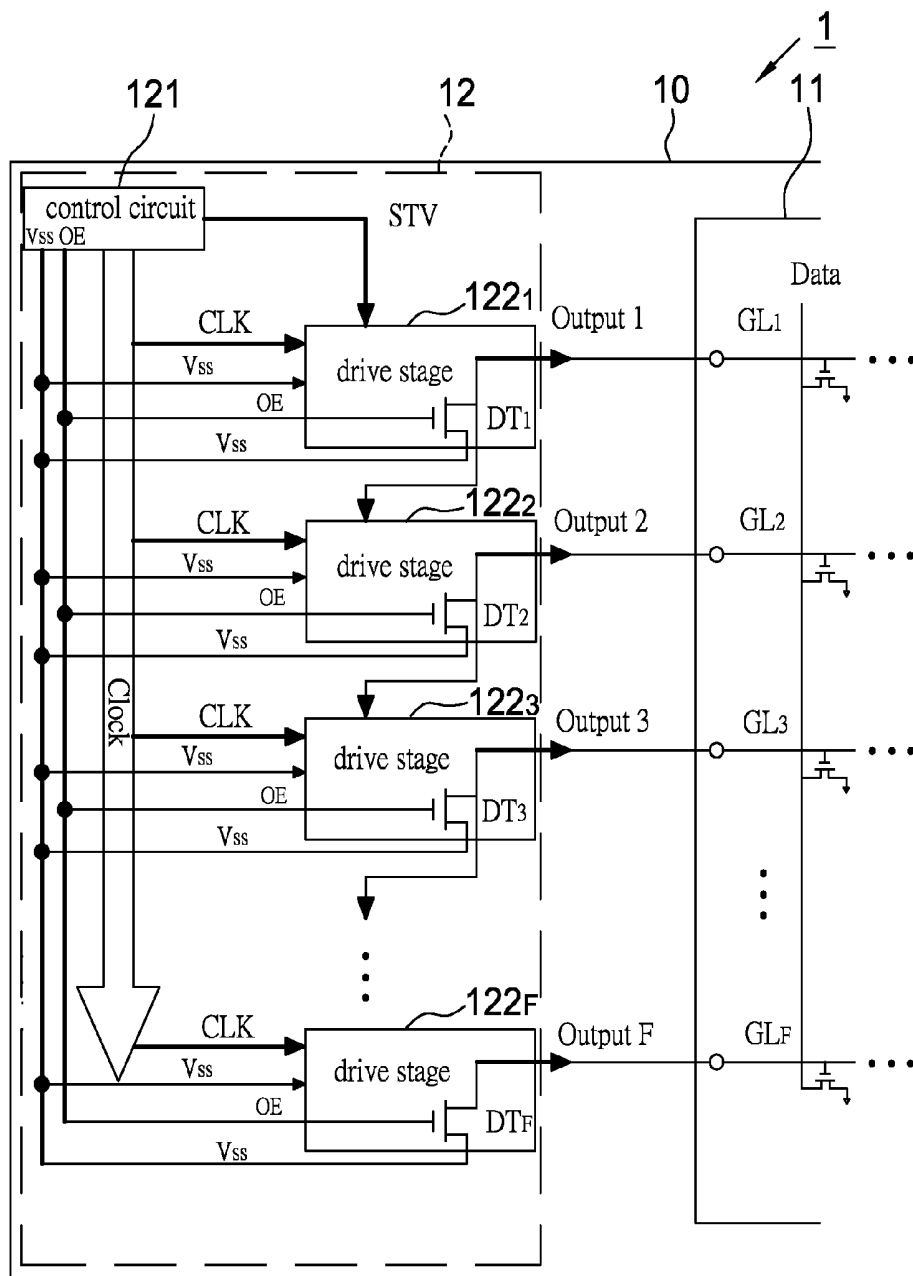


FIG. 4B

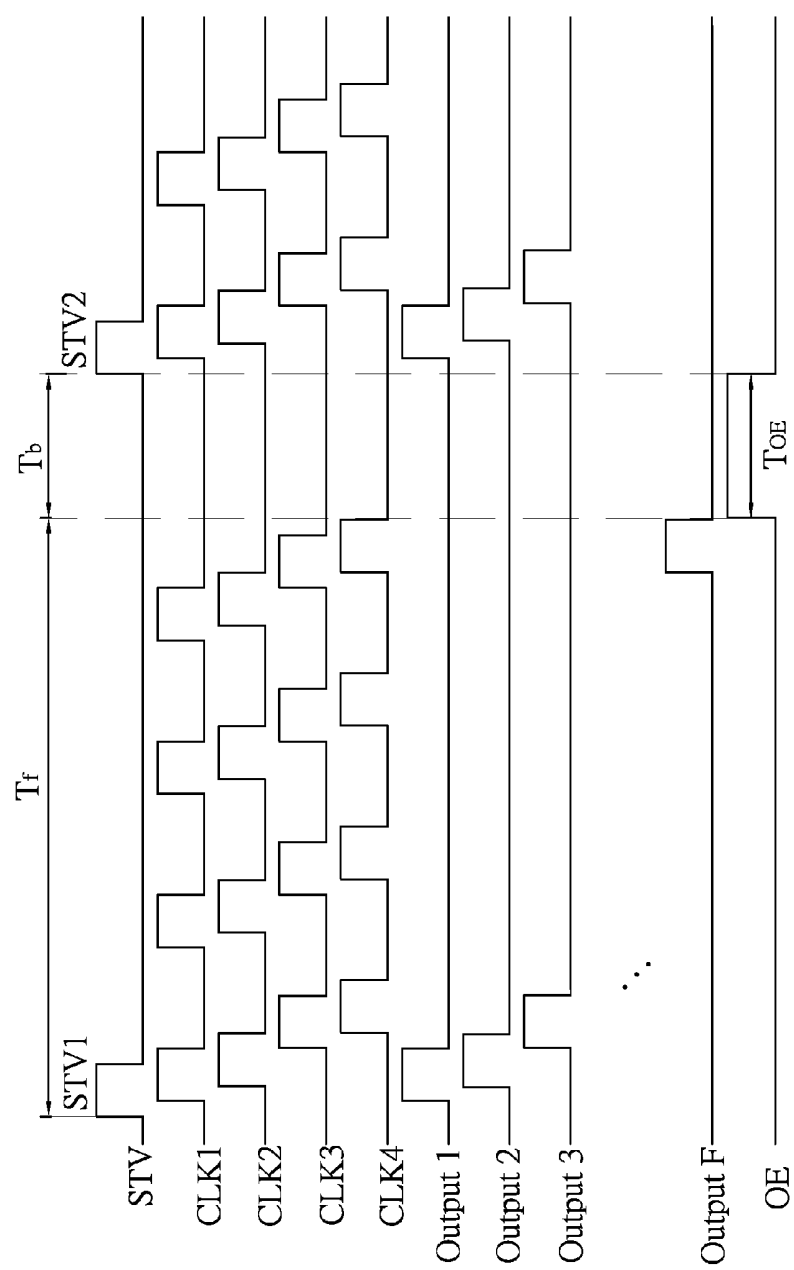


FIG. 5A

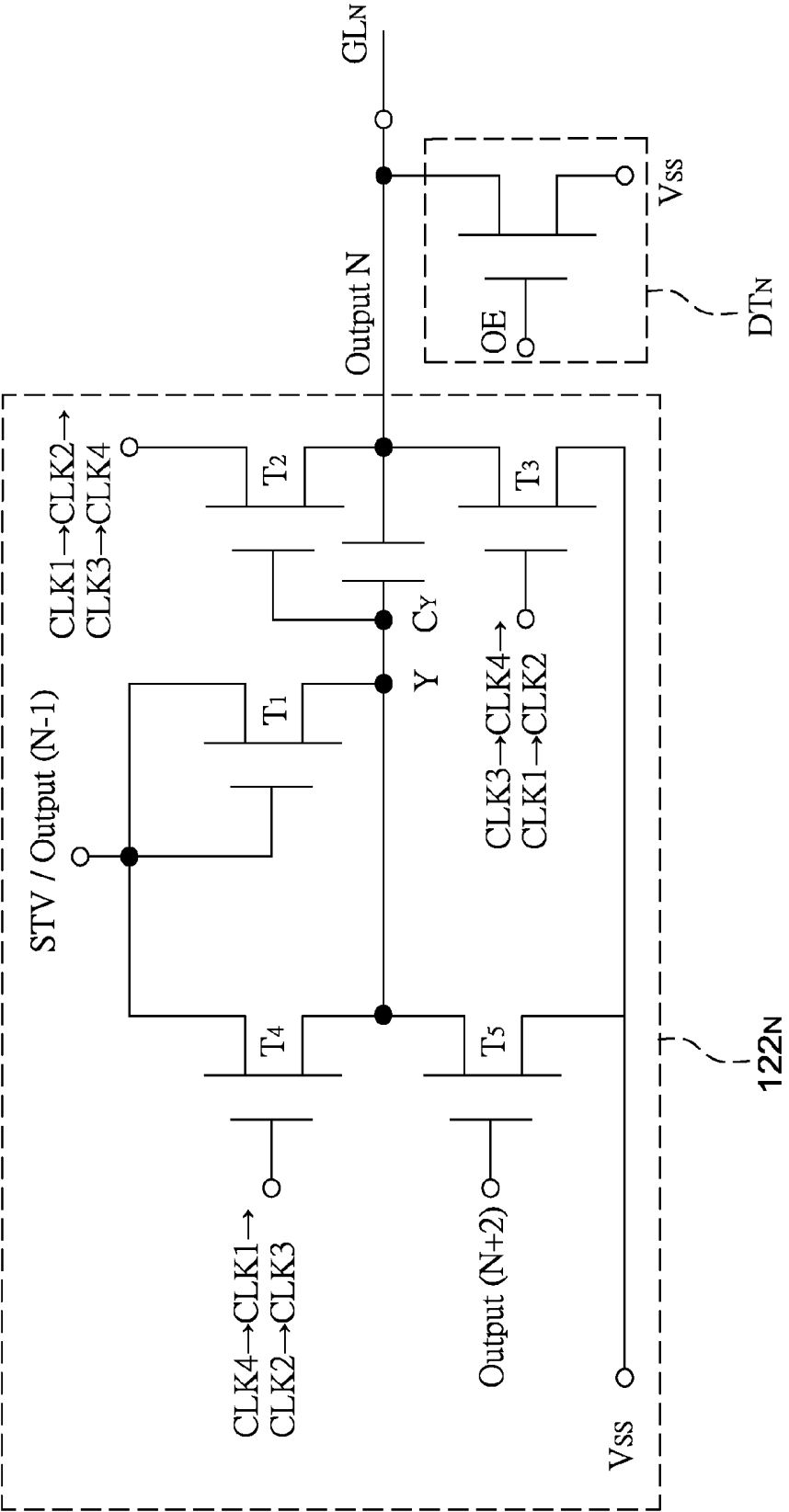


FIG. 5B

rising edge	STV	CLK1	CLK2	CLK3	CLK4
NODE Y	H	H	H	L	L
Output1	^H STV CLK1 overlap	H	^H CLK1 CLK2 overlap	L	L
T ₁	ON	^{ON} STV CLK1 overlap	^{ON} STV CLK2 overlap	OFF	OFF
T ₂	ON	ON	ON	OFF	OFF
T ₃	OFF	OFF	OFF	ON	OFF
T ₄	OFF	OFF	OFF	OFF	ON
T ₅	OFF	OFF	OFF	ON	OFF

FIG. 5C

INTEGRATED GATE DRIVER CIRCUIT AND LIQUID CRYSTAL PANEL

CROSS REFERENCE TO RELATED APPLICATION

[0001] This application claims the priority benefit of Chinese Patent Application Number 201210198895.5, filed on Jun. 14, 2012, the full disclosure of which is incorporated herein by reference.

BACKGROUND

[0002] 1. Field of the Disclosure

[0003] This disclosure generally relates to a liquid crystal display and, more particularly, to an integrated gate driver circuit and a liquid crystal panel using the same.

[0004] 2. Description of the Related Art

[0005] The conventional liquid crystal display generally includes a plurality of gate driver circuits configured to drive a pixel matrix. In order to reduce the manufacturing cost and to efficiently use the substrate space, gate drivers and the pixel matrix can both be formed on the substrate surface, wherein said gate drivers are named the integrated gate driver circuit.

[0006] Referring to FIG. 1, it shows a schematic block diagram of the conventional integrated gate driver circuit **9** including a control circuit **91** and a plurality of drive stages **92₁-92₄...**. The control circuit **91** outputs a plurality of clock signals CLK to the drive stages **92₁-92₄...**, and the clock signals CLK include, for example, CLK1-CLK4, refer to FIG. 2. The drive stages **92₁-92₄...** respectively output an output signal Output 1-Output 4... for driving one gate line.

[0007] Referring to FIG. 2, it shows a timing diagram of the clock signals and the output signals of the integrated gate driver circuit **9** shown in FIG. 1. Firstly the control circuit **91** outputs a start vertical frame signal STV to the first drive stage **92₁** and then sequentially outputs a part of the clock signals CLK1-CLK4 (e.g. CLK1-CLK3) to every drive stage. After receiving a part of the clock signals CLK, the first drive stage **92₁** outputs an output signal Output 1, which is a replica of the first waveform of the clock signal CLK1; after receiving a part of the clock signals CLK the second drive stage **92₂** outputs an output signal Output 2, which is a replica of the first waveform of the clock signal CLK2; after receiving a part of the clock signals CLK the fifth drive stage **92₅** outputs an output signal Output 3, which is a replica of the second waveform of the clock signal CLK1; after receiving a part of the clock signals CLK the sixth drive stage **92₆** outputs an output signal Output 4, which is a replica of the second waveform of the clock signal CLK2; and so on.

[0008] In order to reduce the power consumption of the integrated gate driver circuit **9**, the control circuit **91** will stop outputting any clock signal to the drive stages **92₁-92₄...** between two image frames; that is, in a time interval after the last drive stage outputs an output signal Output n of a first image frame and before the first drive stage **92₁** outputs an output signal Output 1 of a second image frame, referring to FIG. 3, the control circuit **91** does not output any clock signal. However, during the time interval that the drive stages **92₁-92₄...** do not receive any clock signal, the voltage value of the output signals Output 1-Output n... may have the voltage fluctuation as shown in FIG. 3, and this voltage fluctuation can influence the gate driving signals in the second image frame.

[0009] Accordingly, the present disclosure further provides an integrated gate driver circuit and a liquid crystal panel that can eliminate the voltage fluctuation on the gate lines in a blanking period between two image frames.

SUMMARY

[0010] The present disclosure provides an integrated gate driver circuit and a liquid crystal panel that utilize a plurality of discharge transistors to discharge every gate line within the blanking period between two frame periods thereby eliminating the voltage fluctuation on the gate lines in the blanking period.

[0011] The present disclosure further provides an integrated gate driver circuit and a liquid crystal panel that generate a discharge enabling signal within the blanking period between two frame periods so as to discharge the gate lines.

[0012] The present disclosure provides an integrated gate driver circuit includes a control circuit, a drive stage and a discharge transistor. The control circuit is configured to output a plurality of clock signals within a frame period and output a discharge enabling signal within a blanking period. The drive stage receives the clock signals and includes an output terminal configured to output a gate driving signal. The discharge transistor is coupled to the output terminal of the drive stage and configured to discharge the output terminal according to the discharge enabling signal.

[0013] The present disclosure further provides a liquid crystal panel includes a substrate, a thin film transistor matrix and an integrated gate driver circuit. The thin film transistor matrix is formed on the substrate and has a plurality of gate lines. The integrated gate driver circuit is formed on the substrate and configured to drive the thin film transistor matrix. The integrated gate driver circuit includes a control circuit, a drive stage and a discharge transistor. The control circuit is configured to output a plurality of clock signals within a frame period and output a discharge enabling signal within a blanking period. The drive stage receives the clock signals and includes an output terminal configured to output a gate driving signal. The discharge transistor is coupled to the output terminal of the drive stage and configured to discharge the output terminal according to the discharge enabling signal.

[0014] The present disclosure further provides an integrated gate driver circuit includes a control circuit and a drive stage. The control circuit is configured to output a plurality of clock signals within a frame period and output a discharge enabling signal within a blanking period. The drive stage receives the clock signals, and has an output terminal configured to output a gate driving signal and a discharge transistor coupled to the output terminal and configured to discharge the output terminal according to the discharge enabling signal.

[0015] In one aspect, each of the drive stages includes an operating transistor having a control terminal, a first terminal and a second terminal. The control terminal receives the clock signals. The first terminal or the second terminal is coupled to the output terminal.

[0016] In one aspect, the blanking period is a time interval after the gate driving signal outputted by a last drive stages of the plurality of drive stages and before a next start vertical frame signal; and preferably, the blanking period is between a falling edge of the gate driving signal outputted by the last drive stage of the plurality of drive stages and a rising edge of the next start vertical frame signal.

[0017] In one aspect, the control circuit has a negative voltage source configured to output a negative voltage. The first terminal of the discharge transistor is coupled to the terminal; the second of the discharge transistor is coupled to the negative voltage source; and the control terminal of the discharge transistor receives the discharge enabling signal.

[0018] In one aspect, a signal duration of the discharge enabling signal is smaller than or equal to the blanking period.

[0019] In the integrated gate driver circuit and a liquid crystal panel according to the embodiment of the present disclosure, as the control circuit does not output any clock signal to the drive stages within the blanking period, the drive stages are floated to caused the voltage rise on the output terminal. Therefore, the present disclosure utilizes the discharge enabling signal to discharge the output terminal of every drive stage within the blanking period so as to eliminate the voltage fluctuation on the output terminal and the gate lines of the liquid crystal panel within the blanking period.

BRIEF DESCRIPTION OF THE DRAWINGS

[0020] Other objects, advantages, and novel features of the present disclosure will become more apparent from the following detailed description when taken in conjunction with the accompanying drawings.

[0021] FIG. 1 shows a schematic block diagram of the conventional integrated gate driver circuit.

[0022] FIG. 2 shows a timing diagram of the integrated gate driver circuit shown in FIG. 1.

[0023] FIG. 3 shows a schematic diagram of output signals of the first drive stage and the last drive stage of the conventional integrated gate driver circuit.

[0024] FIGS. 4A and 4B respectively show a schematic diagram of the liquid crystal panel and the integrated gate driver circuit according to an embodiment of the present disclosure.

[0025] FIG. 5A shows a timing diagram of the integrated gate driver circuit according to the embodiment of the present disclosure.

[0026] FIG. 5B shows a circuit diagram of one drive stage of the integrated gate driver circuit according to the embodiment of the present disclosure.

[0027] FIG. 5C shows an operational schematic diagram of the drive stage shown in FIG. 5B, wherein the drive stage is a first drive stage.

DETAILED DESCRIPTION OF THE EMBODIMENT

[0028] It should be noted that, wherever possible, the same reference numbers will be used throughout the drawings to refer to the same or like parts.

[0029] Referring to FIG. 4A, it shows a schematic block diagram of the liquid crystal panel according to an embodiment of the present disclosure. The liquid crystal panel 1 includes a substrate 10, a thin film transistor matrix 11 and an integrated gate driver circuit 12. The substrate 10 may be a glass substrate or a flexible substrate for forming a thin film transistor matrix in general liquid crystal panels.

[0030] The thin film transistor matrix 11 is formed on the substrate 10 and includes a plurality of gate lines GL_1 - GL_F respectively connected to a row of thin film transistors, wherein the method of forming a thin film transistor matrix on a substrate is well known and recorded in documents and thus details thereof are not described herein.

[0031] The integrated gate driver circuit 12 is formed on the substrate 10 together with the thin film transistor matrix 11 and configured to drive the thin film transistor matrix 11. The integrated gate driver circuit 12 includes a control circuit 121, a plurality of drive stages 122₁-122_F and a plurality of discharge transistors DT₁-DT_F, wherein the first terminal of the discharge transistors DT₁-DT_F is respectively connected to the drive stages 122₁-122_F.

[0032] Further referring to FIG. 5A, the control circuit 121 is configured to output a plurality of clock signals CLK within a frame period T_f and output a discharge enabling signal or an output enable signal OE within a blanking period T_b , wherein the control circuit 121 does not output the clock signals CLK within the blanking period T_b . The control circuit 121 further includes a negative voltage source configured to provide a negative voltage V_{SS} (or a low voltage, for example -5 volts to -10 volts, but not limited to) to each of the drive stages 122₁-122_F and each of the discharge transistors DT₁-DT_F. In another embodiment, the negative voltage or the low voltage provided to the drive stages 122₁-122_F may be different from that provided to the discharge transistors DT₁-DT_F.

[0033] Each of the drive stages 122₁-122_F receives the clock signals CLK and has an output terminal, and the drive stages 122₁-122_F respectively output a gate driving signal Output 1-Output F to one of the gate lines GL_1 - GL_F . It is appreciated that each of the gate lines GL_1 - GL_F is configured to drive a row of thin film transistors of the thin film transistor matrix 11.

[0034] Each of the discharge transistors DT₁-DT_F is coupled to the output terminal of one of the drive stages 122₁-122_F and one of the gate lines GL_1 - GL_F , and configured to discharge the output terminal and the associated gate lines GL_1 - GL_F according to the discharge enabling signal OE. Each of the discharge transistors DT₁-DT_F includes a first terminal, a second terminal and a control terminal, wherein the first terminal is coupled to the output terminal and one of the gate lines GL_1 - GL_F ; the second terminal is coupled to the negative voltage V_{SS} ; and the control terminal receives the discharge enabling signal OE so as to accordingly discharge the output terminal and the associated gate lines GL_1 - GL_F ; that is, when the control terminal receives the discharge enabling signal OE, the discharge transistors DT₁-DT_F are turned on so as to discharge the output terminal and the associated gate lines GL_1 - GL_F via the second terminal, e.g. discharging to the negative voltage V_{SS} herein. In the embodiment of the present disclosure, the discharge transistors DT₁-DT_F may be thin film transistors that are formed on the substrate 10 together with the drive stages 122₁-122_F and the thin film transistor matrix 11. In another embodiment, the discharge transistors DT₁-DT_F may be respectively included in the drive stages 122₁-122_F as shown in FIG. 4B. In this embodiment, each of the discharge transistors DT₁-DT_F is coupled to one of the gate lines GL_1 - GL_F through the output terminal of one of the drive stages 122₁-122_F, and configured to discharge the associated gate lines GL_1 - GL_F according to the discharge enabling signal OE. Each of the discharge transistors DT₁-DT_F includes a first terminal, a second terminal and a control terminal, wherein the first terminal is coupled to one of the gate lines GL_1 - GL_F through the output terminal; the second terminal is coupled to the negative voltage V_{SS} ; and the control terminal receives the discharge enabling signal OE so as to accordingly discharge the associated gate lines GL_1 - GL_F ; that is, when the control terminal receives the discharge enabling signal OE, the discharge transistors DT₁-

DT_F are turned on so as to discharge the associated gate lines GL_1 - GL_F via the second terminal to the negative voltage V_{SS} .

[0035] Referring to FIG. 5A, it shows a timing diagram of the clock signals CLK1-CLK4 and the output signals Output 1-Output F of the integrated gate driver circuit according to the embodiment of the present disclosure. In the beginning of every frame period T_f , the control circuit 121 first outputs a start vertical frame signal STV (e.g. STV1 and STV2) to a first drive stage 122₁ of the plurality of drive stages, wherein the frame period T_f is referred to a time interval that the integrated gate driver circuit 12 drives the gate lines GL_1 - GL_F once. Between two adjacent frame periods, as the control circuit 121 does not output any clock signal and does not drive any gate line in a time interval, this time interval is referred to the blanking period T_b herein.

[0036] The blanking period T_b is a time interval after a last drive stage 122_F of the plurality of drive stages outputting the gate driving signal Output F and before a next start vertical frame signal STV2; preferably, the blanking period T_b is between a falling edge of the gate driving signal Output F outputted by the last drive stage 122_F and a rising edge of the next start vertical frame signal STV2.

[0037] The integrated gate driver circuit and the liquid crystal panel according to the embodiment of the present disclosure generate the discharge enabling signal OE to the discharge transistors DT_1 - DT_F within the blanking period T_b so as to discharge the output terminal and the gate lines GL_1 - GL_F through the discharge transistors DT_1 - DT_F . Therefore, a signal duration T_{OE} of the discharge enabling signal OE is preferably smaller than or equal to the blanking period T_b .

[0038] Referring to FIG. 5B, it shows a circuit diagram of the Nth drive stage 122_N and the Nth discharge transistor DT_N of the integrated gate driver circuit shown in FIG. 4A. The Nth drive stage 122_N includes a first transistor T_1 , a second transistor T_2 , a third transistor T_3 , a fourth transistor T_4 and a fifth transistor T_5 , wherein the transistors T_1 - T_5 may be thin film transistors and formed on the substrate 10 together with the thin film transistor matrix 11 and the discharge transistors DT_1 - DT_F . The output terminal of the Nth drive stage 122_N is coupled to the Nth discharge transistor DT_N and outputs a gate driving signal Output N to drive one gate line GL_N .

[0039] A first terminal of the first transistor T_1 is coupled to a control terminal of the first transistor T_1 and receives a start vertical frame signal STV or a gate driving signal Output (N-1) outputted by a previous drive stage 122_{N-1}. A second terminal of the first transistor T_1 is coupled to a node Y, wherein the node Y is coupled to the output terminal of the Nth drive stage 122_N and the gate line GL_N through a capacitor C_Y , which is configured to maintain the voltage on the node Y. In another embodiment, the capacitor C_Y may not be implemented.

[0040] A first terminal of the second transistor T_2 receives the clock signals CLK and a second terminal of the second transistor T_2 is coupled to the output terminal and the gate line GL_N . A control terminal of the second transistor T_2 is coupled to the node Y. In this embodiment, the first terminal may receive the clock signals in a sequence CLK1, CLK2, CLK3 and CLK4 shown in FIG. 5A.

[0041] A first terminal of the third transistor T_3 is coupled to the output terminal and the gate line GL_N . A control terminal of the third transistor T_3 receives the clock signals CLK and a second terminal of the third transistor T_3 is coupled to the negative voltage V_{SS} . In this embodiment, the control termi-

nal may receive the clock signals in a sequence CLK3, CLK4, CLK1 and CLK2 shown in FIG. 5A.

[0042] A first terminal of the fourth transistor T_4 is coupled to the first terminal and the control terminal of the first transistor T_1 so as to receive the start vertical frame signal STV or the gate driving signal Output (N-1) of the previous drive stage 122_{N-1}. A second terminal of the fourth transistor T_4 is coupled to the node Y, and a control terminal of the fourth transistor T_4 receives the clock signals CLK. In this embodiment, the control terminal may receive the clock signals in a sequence CLK4, CLK1, CLK2 and CLK3 shown in FIG. 5A.

[0043] A first terminal of the fifth transistor T_5 is coupled to the node Y. A second terminal of the fifth transistor T_5 is coupled to the negative voltage V_{SS} and a control terminal of the fifth transistor T_5 is coupled to a second next drive stage 122_(N+2) of the Nth drive stage 122_N to receive the gate driving signal Output (N+2).

[0044] Referring to FIG. 5C, it shows an operational schematic diagram of the drive stage shown in FIG. 5B, wherein the drive stage is a first drive stage herein.

[0045] In the first drive stage 122₁, the control circuit 121 outputs a start vertical frame signal STV1 to the first drive stage 122₁ at the beginning of one frame period T_f and then the control circuit 121 sequentially outputs the clock signals CLK1, CLK2, CLK3 and CLK4 to the first drive stage 122₁ as shown in FIG. 5A. FIG. 5C shows the operating states of the transistors T_1 - T_5 when sequentially receiving the start vertical frame signal STV1 and the clock signals CLK1-CLK4 and the voltages on the node Y and gate driving signal Output 1, wherein "H" indicates a digit value "1" and "L" indicates a digit value "0" and actual voltage values associated with "H" and "L" may be determined according to actual applications. For example in one embodiment, "H" may be +15 volts and "L" may be -5 volts, but not limited thereto.

[0046] In FIG. 5A, when the last drive stage 122_F outputs a gate driving signal Output F to drive the last gate line GL_F of the thin film transistor matrix 11, one frame period T_f is ended. Next, when the control circuit 121 sends another start vertical frame signal STV2, a next frame period T_f is started. More specifically speaking, the frame period T_f is a time interval that the integrated gate driver circuit 12 drives the gate lines GL_1 - GL_F once; that is, a time interval between a rising edge of the start vertical frame signal STV and a falling edge of the gate driving signal Output F outputted by the last drive stage 122_F.

[0047] It should be mentioned that a circuit structure of every drive stage of the present disclosure is not limited to that shown in FIG. 5B as long as the circuit structure includes an operating transistor and an output terminal, and a control terminal of the operating transistor receives the clock signals CLK so as to discharge the output terminal and the gate line coupled to a first terminal or a second terminal of the operating transistor in at least a part of the frame period T_f . For example, the operating transistor in FIG. 5B is the third transistor T_3 , and when the control terminal of the third transistor T_3 is turned on by the clock signals, the third transistor T_3 may discharge the output terminal coupled to the first terminal thereof and the associated gate line. It should be mentioned that charges on the output terminal are not limited to be discharged to the negative voltage V_{SS} or a low voltage through the operating transistor, and the charges may be discharged to a signal source of the clock signals in other embodiments. In the present disclosure, the drive stages of the integrated gate driver circuit may use any proper circuit struc-

ture as long as discharge transistors DT_1 - DT_F are respectively disposed at the output terminal of every drive stage and the discharge enabling signal OE is sent to the discharge transistors DT_1 - DT_F within the blanking period T_b between two image frames so as to discharge the output terminals and the gate lines GL_1 - GL_F . The blanking period T_b and/or the frame period T_f may be determined according to an actual size of the liquid crystal panel.

[0048] As mentioned above, in the conventional integrated gate driver circuit the voltage fluctuation can occur on the gate line within a blanking period between two image frames so as to influence the image output. Therefore, the present disclosure further provides an integrated gate driver circuit and a liquid crystal display (FIGS. 4A and 4B) that utilize a discharge transistor to discharge the output voltage within a blanking period between two image frames so as to effectively eliminate the voltage fluctuation on the gate lines.

[0049] Although the disclosure has been explained in relation to its preferred embodiment, it is not used to limit the disclosure. It is to be understood that many other possible modifications and variations can be made by those skilled in the art without departing from the spirit and scope of the disclosure as hereinafter claimed.

What is claimed is:

1. An integrated gate driver circuit, comprising:
 - a control circuit configured to output a plurality of clock signals within a frame period and output a discharge enabling signal within a blanking period;
 - a drive stage receiving the clock signals and comprising an output terminal configured to output a gate driving signal; and
 - a discharge transistor coupled to the output terminal of the drive stage and configured to discharge the output terminal according to the discharge enabling signal.
2. The integrated gate driver circuit as claimed in claim 1, wherein the control circuit does not output the clock signals within the blanking period.
3. The integrated gate driver circuit as claimed in claim 1, wherein the control circuit comprises a negative voltage source configured to provide a negative voltage.
4. The integrated gate driver circuit as claimed in claim 3, wherein the negative voltage is provided to the drive stage.
5. The integrated gate driver circuit as claimed in claim 3, wherein the discharge transistor has a first terminal coupled to the output terminal, a second terminal coupled to the negative voltage source, and a control terminal receiving the discharge enabling signal.
6. The integrated gate driver circuit as claimed in claim 1, wherein the control circuit further outputs a start vertical frame signal to a first drive stage in the beginning of the frame period.
7. The integrated gate driver circuit as claimed in claim 6, wherein the blanking period is between the gate driving signal outputted by a last drive stage and a next start vertical frame signal.

8. The integrated gate driver circuit as claimed in claim 1, wherein a signal duration of the discharge enabling signal is smaller than or equal to the blanking period.

9. The integrated gate driver circuit as claimed in claim 1, wherein the drive stage comprises an operating transistor having a control terminal receiving the clock signals and another terminal coupled to the output terminal.

10. A liquid crystal panel, comprising:

- a substrate;
- a thin film transistor matrix formed on the substrate and comprising a plurality of gate lines;
- an integrated gate driver circuit as claimed in claim 1, formed on the substrate and configured to drive the thin film transistor matrix.

11. The liquid crystal panel as claimed in claim 10, wherein the control circuit does not output the clock signals within the blanking period.

12. The liquid crystal panel as claimed in claim 10, wherein the control circuit comprises a negative voltage source configured to provide a negative voltage.

13. The liquid crystal panel as claimed in claim 12, wherein the negative voltage is provided to the drive stage.

14. The liquid crystal panel as claimed in claim 12, wherein the discharge transistor has a first terminal coupled to the output terminal, a second terminal coupled to the negative voltage source, and a control terminal receiving the discharge enabling signal.

15. The liquid crystal panel as claimed in claim 10, wherein the control circuit further outputs a start vertical frame signal to a first drive stage in the beginning of the frame period.

16. The liquid crystal panel as claimed in claim 15, wherein the blanking period is between the gate driving signal outputted by a last drive stage and a next start vertical frame signal.

17. The liquid crystal panel as claimed in claim 10, wherein a signal duration of the discharge enabling signal is smaller than or equal to the blanking period.

18. The liquid crystal panel as claimed in claim 10, wherein the drive stage comprises an operating transistor having a control terminal receiving the clock signals and another terminal coupled to the output terminal.

19. An integrated gate driver circuit, comprising:

- a control circuit configured to output a plurality of clock signals within a frame period and output a discharge enabling signal within a blanking period; and
- a drive stage receiving the clock signals, and comprising an output terminal configured to output a gate driving signal and a discharge transistor coupled to the output terminal and configured to discharge the output terminal according to the discharge enabling signal.

20. The integrated gate driver circuit as claimed in claim 19, wherein the integrated gate driver circuit is configured to be applied to a liquid crystal panel comprising a substrate and a thin film transistor; the integrated gate driver circuit is formed on the substrate and configured to drive the thin film transistor matrix which is formed on the substrate and comprises a plurality of gate lines.

* * * * *

专利名称(译)	集成栅极驱动电路和液晶面板		
公开(公告)号	US20130335665A1	公开(公告)日	2013-12-19
申请号	US13/771806	申请日	2013-02-20
[标]申请(专利权)人(译)	瀚宇彩晶股份有限公司		
申请(专利权)人(译)	瀚宇彩晶股份有限公司.		
当前申请(专利权)人(译)	瀚宇彩晶股份有限公司		
[标]发明人	TSENG CHUN CHIN LEE YA WEN PAN KUO WEN		
发明人	TSENG, CHUN-CHIN LEE, YA-WEN PAN, KUO-WEN		
IPC分类号	G02F1/133 H03K17/16		
CPC分类号	G02F1/13306 H03K17/16 G09G3/3677 G09G5/008 G09G5/18 G09G2310/0286 G09G2310/08 G09G2330/021 G09G2370/08 G11C19/28 H03K17/161		
优先权	201210198895.5 2012-06-14 CN		
其他公开文献	US9459473		
外部链接	Espacenet USPTO		

摘要(译)

集成栅极驱动器电路包括控制电路，多个驱动级和多个放电晶体管。控制电路被配置为在帧周期内输出多个时钟信号，并在帧周期的消隐周期内输出放电使能信号。每个驱动级接收时钟信号并包括输出端子，其被配置为输出栅极驱动信号。每个放电晶体管耦合到一个驱动级的输出端，并根据放电使能信号对输出端放电，从而消除了消隐期中输出端的电压波动。

